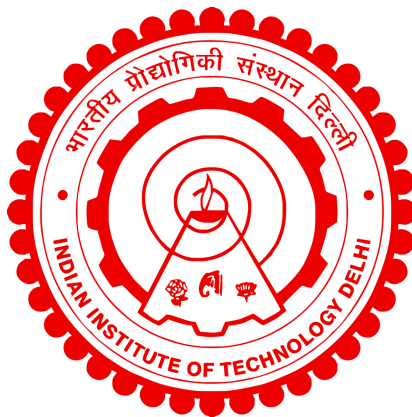


**DESIGN AND FABRICATION OF
PIEZOELECTRIC MICROVALVE FOR ULSI
MICROFLUIDIC APPLICATION**

IMRAN AHMAD



DEPARTMENT OF ELECTRICAL ENGINEERING

INDIAN INSTITUTE OF TECHNOLOGY DELHI

July 2025

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by

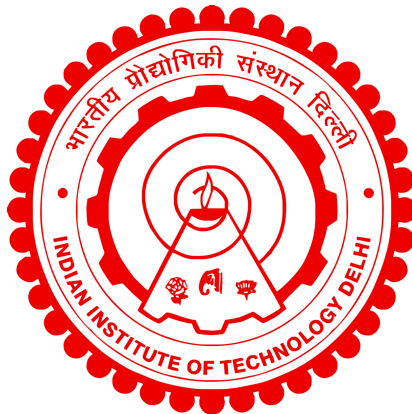
IMRAN AHMAD

Department of Electrical Engineering

Submitted

in partial fulfillment of the requirements of the degree of Doctor of Philosophy

to the



**INDIAN INSTITUTE OF TECHNOLOGY
DELHI**

July 2025

Dedicated to my Parents

Certificate

This is to certify that the thesis entitled “**DESIGN AND FABRICATION OF PIEZOELECTRIC MICROVALVE FOR ULSI MICROFLUIDIC APPLICATION**”, submitted by **Mr. Imran Ahmad** to the Indian Institute of Technology Delhi, for the award of the degree of **Doctor of Philosophy**, is a record of the original, bonafide research work carried out by him under my supervision and guidance. The thesis has reached the standards fulfilling the requirements of the regulations related to the award of the degree.

The results contained in this thesis have not been submitted in part or in full to any other University or Institute for the award of any degree or diploma to the best of my knowledge.

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Imran Ahmad

Imran Ahmad

Abstract

Microfluidics technology has a lot of promise in Lab on chip, drug discovery and combinatorial chemistry applications. However, progress in many applications is hampered by the lack of a scalable, low cost and reliable valve technology. Pneumatically actuated valves have been the mainstay of microfluidic valve technology, but are hard to scale and require a supply of compressed air.

This dissertation focuses on the design, fabrication, and testing of a piezoelectric microvalve integrated with microfluidics through a transfer process. Firstly, a comprehensive study on lead-free materials like P(VDF-TrFE), potassium sodium niobate (KNN), and barium titanate (BaTiO_3) is undertaken. Various methods to create thin films, such as drop casting, spin coating, and screen printing, are explored. A low-temperature process to fabricate the valve using screen printing has been developed using a nanocomposite paste using BaTiO_3 nanopowder and ethyl cellulose. The screen-printed film has been characterized, showing good crystallinity, excellent piezoelectricity ($d_{33} \sim 370 \text{ pm/V}$), and Young's modulus (2.54 GPa). The rheological analysis of the paste exhibits a pseudoplastic effect, which is essential for achieving high-quality printing with minimal force and preventing screen blockages. The electron probe microanalyzer (EPMA) was performed for quantitative analysis of elements present in nanocomposites paste, confirming homogeneous mixing and uniform spatial distribution of elements required to exhibit enhanced piezoelectricity.

Another lead-free piezoelectric nanocomposite materials consisting of P(VDF-TrFE) and KNN have been synthesized. The thin film of the nanocomposite has been characterized, showing good crystallinity and enhanced piezoelectric response ($d_{33} \sim 96 \text{ pm/V}$ for composite-1 and $d_{33} \sim 95 \text{ pm/V}$ for composite-2), an almost 2.5-fold increase compared to the d_{33} of pristine P(VDF-TrFE) film. Nanoindentation was performed to measure Young's modulus and the material's stiffness. The measured Young's modulus was 2.17 GPa for composite-1 and 2.97 GPa for composite-2. The measured stiffness²/load was $\sim 71.9 \text{ GPa}$ for composite-1 and 165 GPa for composite-2.

This thesis has demonstrated two methods for transferring a thin parylene membrane on top of the PDMS microfluidic channel by utilizing parylene-parylene bonding.

Furthermore, a novel low-temperature process for the fabrication of microvalves through screen printing has been developed and demonstrated successfully.

Finally, a straightforward low-temperature drop-casting method was utilized to fabricate piezoelectric microvalves using composite-1. The piezoelectric stack actuator was fabricated on a 2-inch silicon wafer using surface micromachining. The piezoelectric actuator was transferred to the PDMS microchannel through a transfer process for microvalve fabrication. The displacement of the parylene membrane in response to a DC voltage was characterized indirectly using a DC probe station and directly using a 3D optical profiler. The profiler characterization shows a maximum membrane deflection of $\sim 2.847\ \mu\text{m}$ at an actuation voltage of 12 V. Plane actuation was performed by introducing dye at the inlet and studying its flow behavior through optical microscopy to outlet at 12 V, 0 V, and $-12\ \text{V}$, demonstrating valving action. The leakage pressure of the microvalve lies in the range of 32–34 kPa, suggesting that valve operation must be performed below this pressure for safe and reliable operation. The microvalve testing results are encouraging and hold significant promise for advancing microfluidic technologies and laboratory automation.

In summary, this dissertation work provides a novel approach to the fabrication of a piezoelectric microvalve and its integration with microfluidics using the transfer in a facile manner.

सार

माइक्रोफ़ुइडिक्स तकनीक में चिप प्रयोगशाला, दवा खोज और कॉम्बिनेटरियल रसायन विज्ञान अनुप्रयोगों में अपार संभावनाएं हैं। हालाँकि, कई अनुप्रयोगों में प्रगति एक मापनीय, कम लागत वाली और विश्वसनीय वाल्व तकनीक के अभाव के कारण बाधित है। वायवीय रूप से संचालित वाल्व माइक्रोफ़ुइडिक वाल्व तकनीक का मुख्य आधार रहे हैं, लेकिन इन्हें मापना कठिन है और इसके लिए संपीड़ित हवा की आपूर्ति की आवश्यकता होती है। यह शोध प्रबंध एक स्थानांतरण प्रक्रिया के माध्यम से माइक्रोफ़ुइडिक्स के साथ एकीकृत एक पीजोइलेक्ट्रिक माइक्रोवाल्व के डिजाइन, निर्माण और परीक्षण पर केंद्रित है। सबसे पहले, P(VDF-TrFE), पोटेशियम सोडियम नाइओबेट (KNN), और बेरियम टाइटेनेट (BaTiO₃) जैसे सीसा रहित पदार्थों पर एक व्यापक अध्ययन किया गया है। पतली फिल्में बनाने के विभिन्न तरीकों, जैसे ड्रॉप कास्टिंग, स्पिन कोटिंग और स्क्रीन प्रिंटिंग, का पता लगाया गया है। स्क्रीन प्रिंटिंग का उपयोग करके वाल्व बनाने की एक निम्न-तापमान प्रक्रिया विकसित की गई है। BaTiO₃ नैनोपाउडर और एथिल सेलुलोज का उपयोग करके एक नैनोकंपोजिट पेस्ट का उपयोग किया गया है। स्क्रीन-प्रिंटेड फिल्म की विशेषताओं का विश्लेषण किया गया है, जिसमें अच्छी क्रिस्टलीयता, उत्कृष्ट पीजोइलेक्ट्रिसिटी (d₃₃ ~ 370 pm/V) और यंग मापांक (2.54 GPa) प्रदर्शित हुए हैं। पेस्ट का रियोलॉजिकल विश्लेषण एक छद्मप्लास्टिक प्रभाव प्रदर्शित करता है, जो न्यूनतम बल के साथ उच्च-गुणवत्ता वाली प्रिंटिंग प्राप्त करने और स्क्रीन अवरोधों को रोकने के लिए आवश्यक है। इलेक्ट्रॉन प्रोब माइक्रोएनलाइजर (EPMA) का उपयोग नैनोकंपोजिट पेस्ट में मौजूद तत्वों के मात्रात्मक विश्लेषण के लिए किया गया, जिससे बड़ी हुई पीजोइलेक्ट्रिसिटी प्रदर्शित करने के लिए आवश्यक तत्वों के सजातीय मिश्रण और समान स्थानिक वितरण की पुष्टि हुई। P(VDF-TrFE) और KNN से युक्त एक और सीसा-रहित पीजोइलेक्ट्रिक नैनोकंपोजिट सामग्री का संश्लेषण किया गया है। नैनोकंपोजिट की पतली फिल्म की विशेषताएँ निर्धारित की गई हैं, जो अच्छी क्रिस्टलीयता और बड़ी हुई दाबविद्युत प्रतिक्रिया (कंपोजिट-1 के लिए d₃₃ ~ 96 pm/V और कंपोजिट-2 के लिए d₃₃ ~ 95 pm/V) दर्शाती है, जो कि प्राचीन P(VDF-TrFE) फिल्म के d₃₃ की तुलना में लगभग 2.5 गुना वृद्धि है। यंग मापांक और पदार्थ की कठोरता को मापने के लिए नैनोइंडेंटेशन किया गया। मापा गया यंग मापांक कंपोजिट-1 के लिए 2.17 GPa और कंपोजिट-2 के लिए 2.97 GPa था। मापी गई कठोरता²/भार कंपोजिट-1 के लिए ~ 71.9 GPa और कंपोजिट-2 के लिए 165 GPa थी। इस शोध प्रबंध में पैरीलीन-पैरीलीन बंधन का उपयोग करके PDMS माइक्रोफ़ुइडिक चैनल के शीर्ष पर एक पतली पैरीलीन झिल्ली को स्थानांतरित करने की दो विधियों का प्रदर्शन किया गया है। इसके अलावा, स्क्रीन प्रिंटिंग के माध्यम से माइक्रोवाल्वों के निर्माण के लिए एक नवीन निम्न-तापमान प्रक्रिया विकसित और सफलतापूर्वक प्रदर्शित की गई है। अंततः, कंपोजिट-1 का उपयोग करके पीजोइलेक्ट्रिक माइक्रोवाल्वों के निर्माण हेतु एक सरल निम्न-तापमान ड्रॉप-कास्टिंग विधि का उपयोग किया गया। पीजोइलेक्ट्रिक स्टैक एक्ट्यूएटर का निर्माण सतह माइक्रोमशीनिंग का उपयोग करके 2-इंच सिलिकॉन वेफर पर किया गया था। माइक्रोवाल्व निर्माण हेतु एक स्थानांतरण प्रक्रिया के माध्यम से पीजोइलेक्ट्रिक एक्ट्यूएटर को PDMS माइक्रोचैनल में स्थानांतरित किया गया था। डीसी वोल्टेज की प्रतिक्रिया में पैरीलीन झिल्ली के

विस्थापन को अप्रत्यक्ष रूप से डीसी प्रोब स्टेशन का उपयोग करके और प्रत्यक्ष रूप से 3D ऑप्टिकल प्रोफाइलर का उपयोग करके चिह्नित किया गया था। प्रोफाइलर अभिलक्षणन 12 V के एक्चुएशन वोल्टेज पर लगभग 2.847 μm का अधिकतम झिल्ली विक्षेपण दर्शाता है। समतल एक्चुएशन इनलेट में डाई डालकर और 12 V, 0 V, और -12 V पर आउटलेट तक ऑप्टिकल माइक्रोस्कोपी के माध्यम से इसके प्रवाह व्यवहार का अध्ययन करके किया गया, जिससे वाल्विंग क्रिया का प्रदर्शन हुआ। माइक्रोवाल्व का रिसाव दबाव 32-34 kPa की सीमा में है, जो यह सुझाव देता है कि सुरक्षित और विश्वसनीय संचालन के लिए वाल्व संचालन इस दबाव से नीचे किया जाना चाहिए। माइक्रोवाल्व परीक्षण के परिणाम उत्साहजनक हैं और माइक्रोफ़ुइडिक प्रौद्योगिकियों और प्रयोगशाला स्वचालन को आगे बढ़ाने के लिए महत्वपूर्ण संभावनाएं रखते हैं। संक्षेप में, यह शोध प्रबंध एक पीजोइलेक्ट्रिक माइक्रोवाल्व के निर्माण और स्थानांतरण का उपयोग करके माइक्रोफ़ुइडिक्स के साथ इसके एकीकरण के लिए एक नया दृष्टिकोण प्रदान करता है।

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Abbreviations

MEMS	Micro-Electro-Mechanical Systems
PZT	Lead Zirconate Titanate
BaTiO ₃	Barium Titanate
KNN	Potassium Sodium Niobate
PVDF-TrFE	Poly(vinylidene fluoride–trifluoro ethylene)
PDMS	Polydimethylsiloxane
Parylene	Poly-para-xylylene
PR	Photoresist
PFM	Piezoresponse Force Microscopy
DI	Deionized Water
IPA	Isopropyl Alcohol
UV	Ultraviolet
TEM	Tunnelling Electron Microscope
SEM	Scanning Electron Microscope
FESEM	Field Emission Scanning Electron Microscope
EPMA	Electron Probe Microanalyser
XRD	X-ray Diffraction
EDX	Energy Dispersive X-ray Spectroscopy
FTIR	Fourier Transform Infrared Spectroscopy
Raman	Raman Spectroscopy
AFM	Atomic Force Microscope
RIE	Reactive Ion Etching
LDV	Laser Doppler Vibrometer
DC	Direct Current
CVD	Chemical Vapour Deposition
CV	Capacitance–Voltage

IV	Current–Voltage
Si	Silicon
NO	Normally Open
NC	Normally Closed
Mo	Molybdenum
Al	Aluminium
Au	Gold
d_{33}	Piezoelectric Charge Coefficient
ϵ_{33}	Dielectric Constant
FEA	Finite Element Analysis
SU8 2030	Negative Photoresist
AZ 40XT	Positive Photoresist
P-E	Polarization–Electric Field
SMA	Shape Memory Alloy
PTFE	Polytetrafluoroethylene
Teflon-AF	Amorphous Fluoropolymer
DMSO	Dimethyl Sulfoxide